

**Pb Free Plating Product**

## DSEP29-12A



30A, 1200V SwitchMode Single Fast Recovery Epitaxial Diode

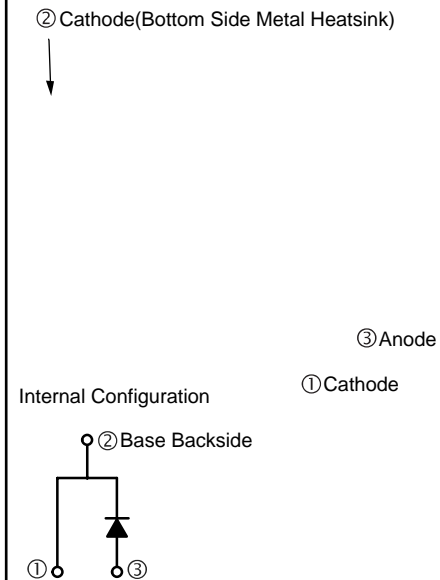
### APPLICATION

- g Freewheeling, Snubber, Clamp
- g Inversion Welder
- g PFC
- g Plating Power Supply
- g Ultrasonic Cleaner and Welder
- g Converter & Chopper
- g UPS

### PRODUCT FEATURE

- g Ultrafast Recovery Time
- g Soft Recovery Characteristics
- g Low Recovery Loss
- g Low Forward Voltage
- g High Surge Current Capability
- g Low Leakage Current

### TO-220AC



### GENERAL DESCRIPTION

DSEP29-12A using latest FRED FAB process(planar passivation pellet) with ultrafast and soft recovery characteristics.

### ABSOLUTE MAXIMUM RATINGS

$T_C=25^{\circ}\text{C}$  unless otherwise specified

Symbol	Parameter	Test Conditions	Values	Unit
$V_R$	Maximum D.C. Reverse Voltage		1200	V
$V_{RRM}$	Maximum Repetitive Reverse Voltage		1200	V
$I_{F(AV)}$	Average Forward Current	$T_C=110^{\circ}\text{C}$	30	A
$I_{F(RMS)}$	RMS Forward Current	$T_C=110^{\circ}\text{C}$	42	A
$I_{FSM}$	Non-Repetitive Surge Forward Current	$T_J=45^{\circ}\text{C}$ , $t=10\text{ms}$ , 50Hz, Sine	300	A
$P_D$	Power Dissipation		105	W
$T_J$	Junction Temperature		-40 to +150	$^{\circ}\text{C}$
$T_{STG}$	Storage Temperature Range		-40 to +150	$^{\circ}\text{C}$
Torque	Module-to-Sink	Recommended $\text{ÄM3 Ä}$	1.1	N·m
$R_{\theta\text{-JC}}$	Thermal Resistance	Junction-to-Case	1.2	$^{\circ}\text{C/W}$
Weight			2.2	g

### ELECTRICAL CHARACTERISTICS

$T_C=25^{\circ}\text{C}$  unless otherwise specified

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$I_{RM}$	Reverse Leakage Current	$V_R=1200\text{V}$	--	--	100	$\mu\text{A}$
		$V_R=1200\text{V}$ , $T_J=125^{\circ}\text{C}$	--	--	1	mA
$V_F$	Forward Voltage	$I_F=30\text{A}$	--	2.15	2.5	V
		$I_F=30\text{A}$ , $T_J=125^{\circ}\text{C}$	--	1.75	--	V
$t_{rr}$	Reverse Recovery Time	$I_F=1\text{A}$ , $V_R=30\text{V}$ , $di_F/dt=-2 \text{ } \text{\$/ V}$	--	30	--	ns
$t_{rr}$	Reverse Recovery Time	$V_R=600\text{V}$ , $I_F=30\text{A}$	--	160	--	ns
$I_{RRM}$	Max. Reverse Recovery Current	$di_F/dt=-2 \text{ } \text{\$/ V}$ , $T_J=25^{\circ}\text{C}$	--	5	--	A
$t_{rr}$	Reverse Recovery Time	$V_R=600\text{V}$ , $I_F=30\text{A}$	--	300	--	ns
$I_{RRM}$	Max. Reverse Recovery Current	$di_F/dt=-2 \text{ } \text{\$/ V}$ , $T_J=725^{\circ}\text{C}$	--	11	--	A

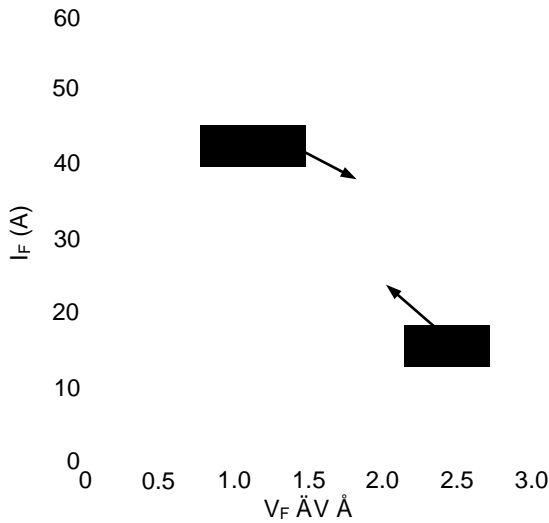


Fig1. Forward Voltage Drop vs Forward Current

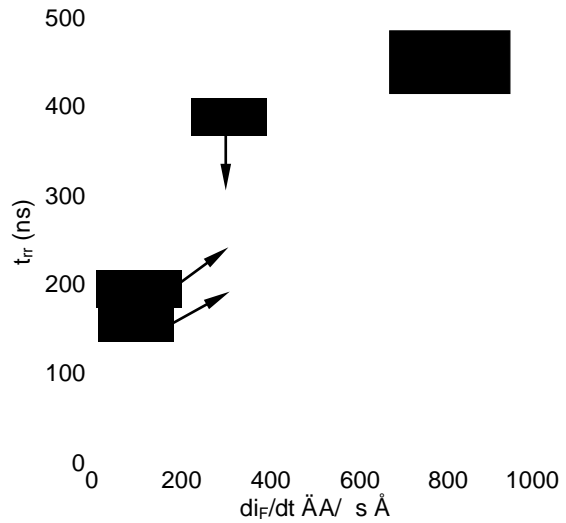


Fig2. Reverse Recovery Time vs  $di_F/dt$

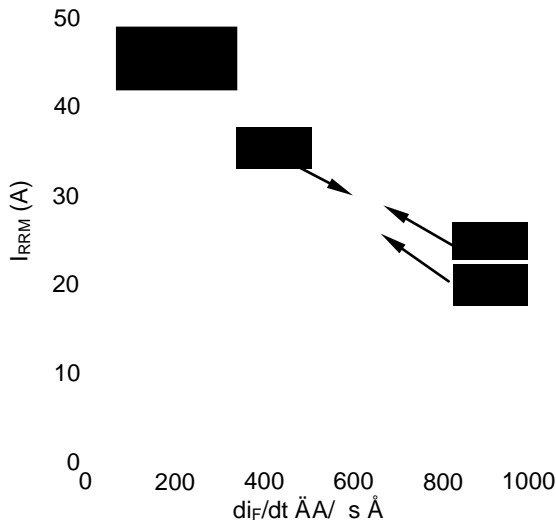


Fig3. Reverse Recovery Current vs  $di_F/dt$

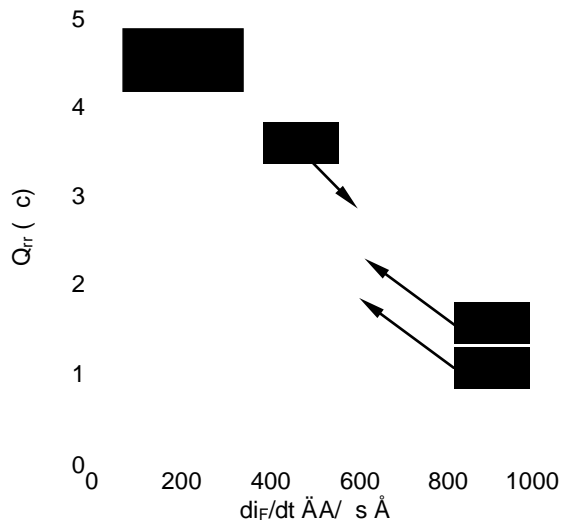


Fig4. Reverse Recovery Charge vs  $di_F/dt$

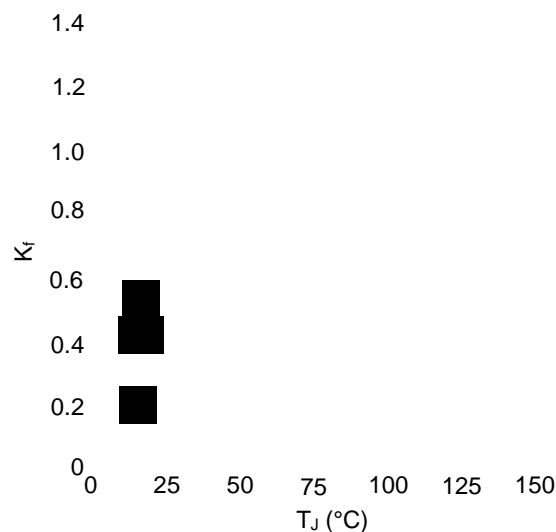


Fig5. Dynamic Parameters vs Junction Temperature

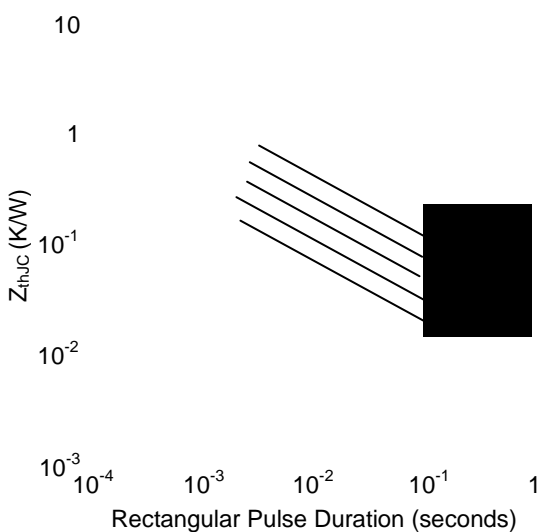


Fig6. Transient Thermal Impedance

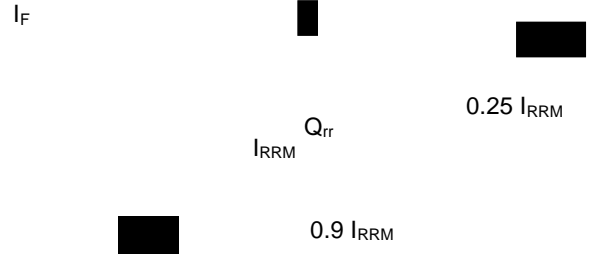


Fig7. Diode Reverse Recovery Test Circuit and Waveform

Dimensions TO-220AC